

ESH2PB, ESH2PC, ESH2PD

Vishay General Semiconductor

AUTOMOTIVE

RoHS

COMPLIANT

HALOGEN FREE

High Current Density Surface Mount Ultrafast Rectifiers



DESIGN SUPPORT TOOLS





PRIMARY CHARACTERISTICS				
I _{F(AV)}	2.0 A			
V_{RRM}	100 V, 150 V, 200 V			
t _{rr}	25 ns			
V_F at $I_F = 2 A$	0.75 V			
T _J max.	175 °C			
Package	SMP (DO-220AA)			
Circuit configuration	Single			

FEATURES

- Very low profile typical height of 1.0 mm
- · Ideal for automated placement
- · Glass passivated pellet chip junction
- Ultrafast recovery times for high frequency
- Low forward voltage drop, low power losses
- Low thermal resistance
- Meets MSL level 1 per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishav.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in secondary rectification and freewheeling for ultrafast switching speeds of AC/DC and DC/DC converters in high temperature for both consumer and automotive applications.

MECHANICAL DATA

Case: SMP (DO-220AA)

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Base P/NHM3 - halogen-free, RoHS-compliant, and automotive grade

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 2 whisker test, HM3 suffix meets JESD 201 class 2 whisker test

Polarity: color band denotes the cathode end

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	ESH2PB	ESH2PC	ESH2PD	UNIT
Device marking code		P2B	P2C	P2D	
Maximum repetitive peak reverse voltage	V _{RRM}	100	150	200	V
Maximum average forward rectified current (fig. 1)	I _{F(AV)}	2.0			Α
Peak forward surge current 10 ms single half sine-wave superimposed on rated load	I _{FSM}	50			Α
Operating junction and storage temperature range	T _J , T _{STG}	-55 to +175			°C

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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Maximum instantaneous forward voltage	I _F = 2 A	T _J = 25 °C	V _F ⁽¹⁾	0.90	0.98	V
		T _J = 125 °C		0.75	0.82	
Maximum reverse current at	In (2)	ı_ (2)	0.2	1.0		
rated V _R		T _J = 125 °C	IR (=)	12.6	25	- μΑ
Maximum reverse recovery time	$I_F = 0.5 \text{ A}, I_R = 1 \text{ A}, I_{rr} = 0.25 \text{ A}$		t _{rr}	-	25	ns
Typical reverse recovery time	$I_F = 1.0 \text{ A}, V_R = 30 \text{ V},$ $dI/dt = 50 \text{ A/}\mu\text{s}, I_{rr} = 10 \% I_{RM}$	T _J = 25 °C	t _{rr}	25	-	- ns
		T _J = 100 °C		35	-	
Typical stored charge	$I_F = 1.0 \text{ A}, V_R = 30 \text{ V},$ $dI/dt = 50 \text{ A/}\mu\text{s}, I_{rr} = 10 \% I_{RM}$	T _J = 25 °C	Q _{rr}	10	-	nC
		T _J = 100 °C		15	-	
Typical junction capacitance	4.0 V, 1 MHz	_	CJ	25	-	pF

Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	ESH2PB	ESH2PC	ESH2PD	UNIT
	R _{0JA} (1)		80		
Typical thermal resistance	R _{0JL} (1)	15			°C/W
	R ₀ JC (1)		22		

Note

(1) Thermal resistance from junction to ambient and junction to lead mounted on PCB with 6.0 mm x 6.0 mm copper pad areas. $R_{\theta JL}$ is measured at the terminal of cathode band. $R_{\theta JC}$ is measured at the top center of the body

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
ESH2PB-M3/84A	0.024	84A	3000	7" diameter plastic tape and reel		
ESH2PB-M3/85A	0.024	85A	10 000	13" diameter plastic tape and reel		
ESH2PBHM3/84A (1)	0.024	84A	3000	7" diameter plastic tape and reel		
ESH2PBHM3/85A (1)	0.024	85A	10 000	13" diameter plastic tape and reel		

Note

(1) Automotive grade



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RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

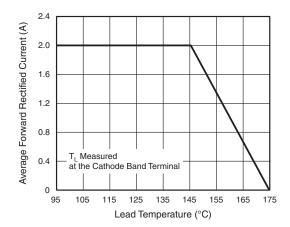


Fig. 1 - Maximum Forward Current Derating Curve

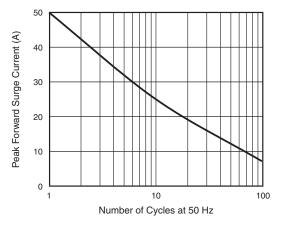


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current

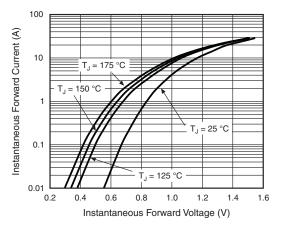


Fig. 3 - Typical Instantaneous Forward Characteristics

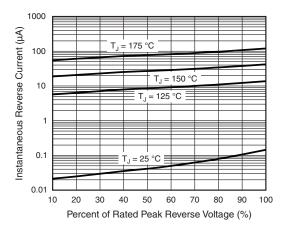


Fig. 4 - Typical Reverse Leakage Characteristics

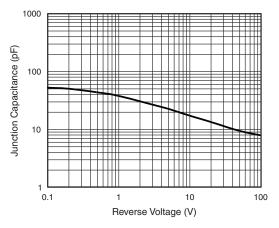


Fig. 5 - Typical Junction Capacitance

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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

SMP (DO-220AA) 0.012 (0.30) REF. Cathode Band ⊕<u>.</u>O 0.053 (1.35) 0.086 (2.18) 0.036 (0.91) 0.074 (1.88) 0.041 (1.05) 0.024 (0.61) 0.142 (3.61) 0.103 (2.60) 0.032 (0.80) 0.126 (3.19) 0.087 (2.20) 0.016 (0.40) 0.158 (4.00) 0.146 (3.70) 0.025 0.030 (0.635) (0.762) 0.105 (2.67) 0.013 (0.35) 0.004 (0.10) 0.045 (1.15) 0.033 (0.85) 0.100 (2.54) 0.050 (1.27) 0.012 (0.30) 0.018 (0.45) 0.000 (0.00) 0.006 (0.15)



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